

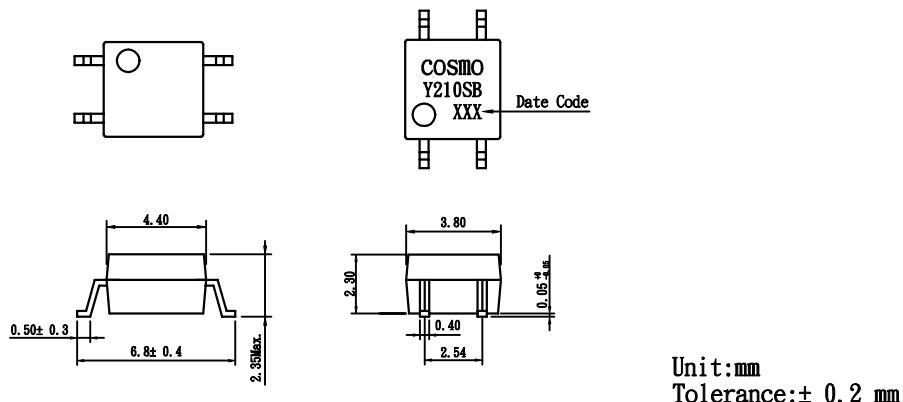
PRODUCT SPECIFICATION

COSMO
ELECTRONICS CO., LTD.

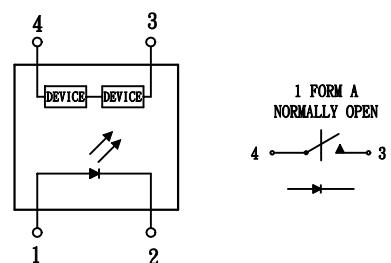
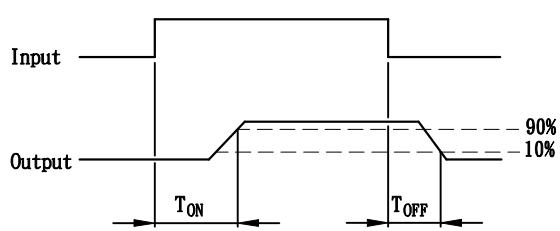
PHOTO MOS RELAYS:
KAQY210SB

SHEET 1 OF 7

- OUTSIDE DIMENSION :



- Turn on/Turn off time



Absolute Maximum Ratings ($T_A=25^\circ C$)

Emitter (Input)

Reverse Voltage	5.0V
Continuous Forward Current	50mA
Peak Forward Current (1s)	1A
Power Dissipation.	100mW
Derate Linearly from 25° C	1.3mW/° C

Detector (Output)

Output Breakdown Voltage	± 350V
Continous Load Current	± 130mA

Power Dissipation	500mW
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General Characteristics

Isolation Test Voltage.	1500VAC _{RMS}
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Isolation Resistance

$V_{10} = 500V, T_A = 25^\circ C$	$\geq 10^{10} \Omega$
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Total Power Dissipation	550mW
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Derate Linearly form 25° C	2.5mW/° C
Storage Temperature Range	-40 to +150° C
Operating Temperature Range.	-40 to +85° C
Junction Temperature	100° C
Soldering Temperature, 2mm from case, 10 sec.	260° C

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Characteristics

($T_A = 25^\circ C$)

Description	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Emitter (Input)						
Forward Voltage	V_F		1.2	1.5	V	$I_F = 10mA$
Operation Input Current	I_{FON}			5	mA	$V_L = \pm 20V, I_L = 100mA, t = 10 ms$
Recovery Input Current	I_{FOFF}	0.05			mA	$V_L = \pm 20V, I_L = < 5\mu A$
Deterctor (Output)						
Output Breakdown Voltage	V_B	350			V	$I_B = 50\mu A$
Output Off-State Leakage	I_{TOFF}		0.7	2	μA	$V_T = 100V, I_F = 0mA$
I/O Capacitance	C_{ISO}		6		pF	$I_F = 0, f = 1MHz$
ON Resistance	R_{ON}		28	35	Ω	$I_L = 100mA, I_F = 10mA$
Turn-on Time	T_{ON}		0.1	0.5	ms	$I_F = 10mA, V_L = \pm 20V$
Turn-off Time	T_{OFF}		0.3	0.5	ms	$t = 10ms, I_L = \pm 100mA$

Mos Relay Schematic and Wiring Diagrams						
Type	Schematic	Output configuration	Load	Con-nection	Wiring diagram	
KAQY210SB	 1a	AC/DC	-			

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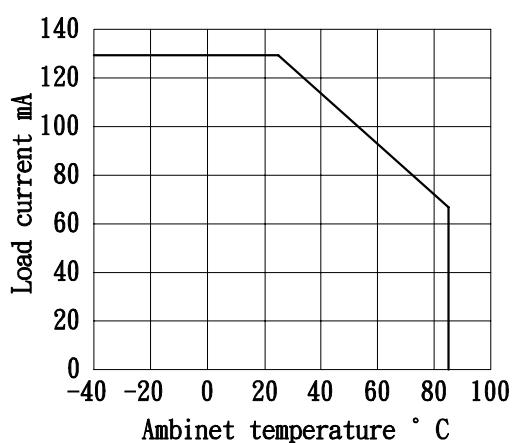
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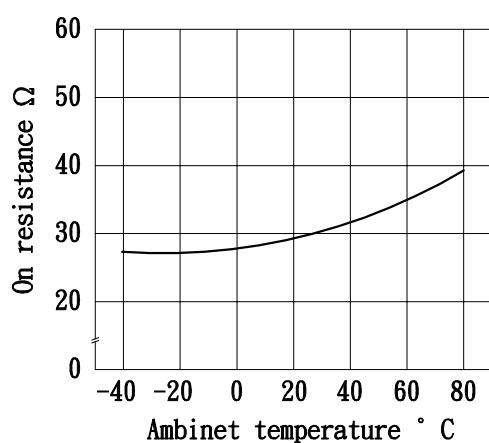
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DATA CURVE

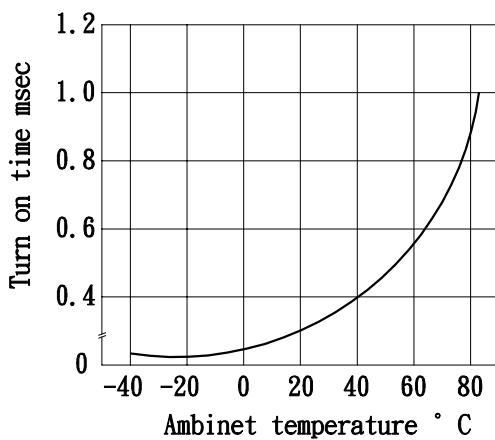
Load current vs. ambient temperature
Allowable ambient temperature:
-40° C+85° C



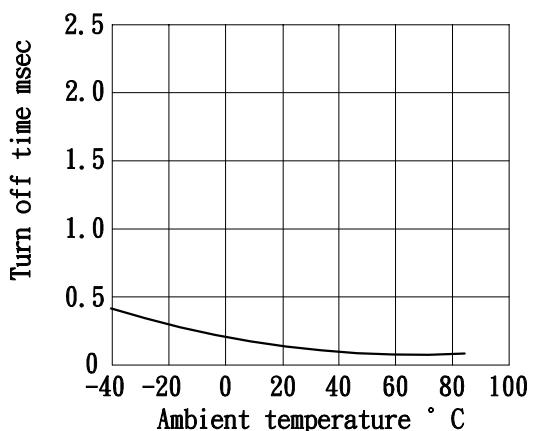
On resistance vs. ambient temperature
Across terminals 3 and 4 pin
LED current: 5mA
Continuous load current: 130 mA(DC)



Turn on time vs. ambient temperature
Load voltage 350 V(DC)
LED current :5mA
Continuous load current: 130mA(DC)



Turn off time vs. ambient temperature
LED current: 5mA; Load voltage: 350V(DC)
Continuous load current: 130mA(DC)

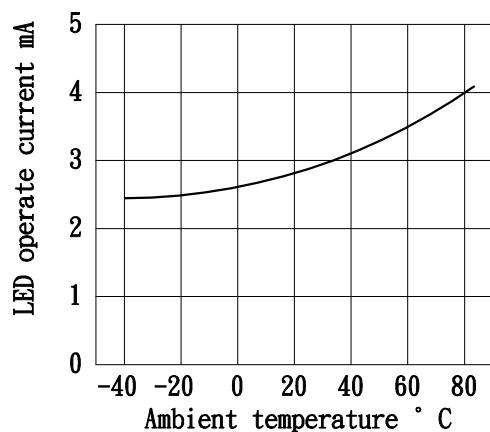


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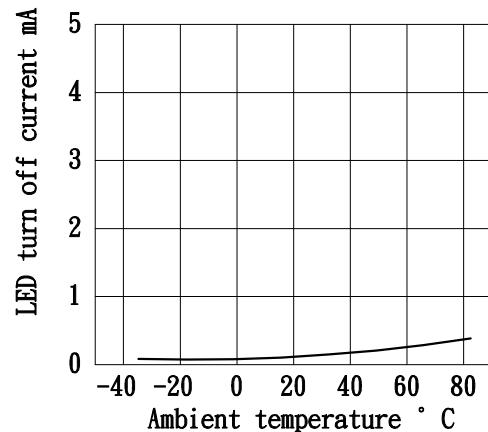
LED operate vs. ambient temperature
Load voltage: 350V(DC)

Continuous load current: 130mA(DC)



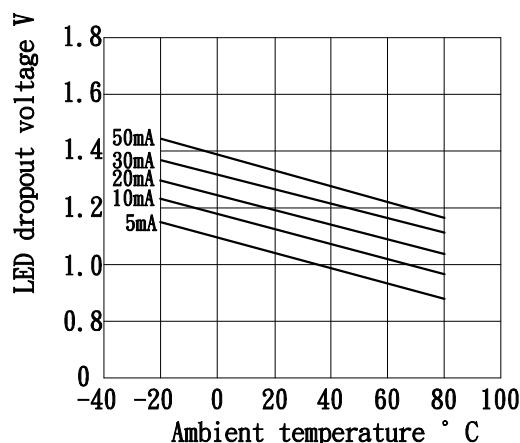
LED turn off current vs. ambient temperature
Load voltage: 350V(DC)

Continuous load current: 130mA(DC)



LED dropout voltage vs. ambient temperature

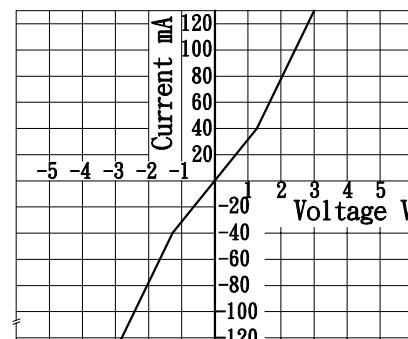
LED current: 5 to 50mA



Voltage vs. current characteristics of output at MOS FET portion

Measured portion: across terminals 3 and 4 pin

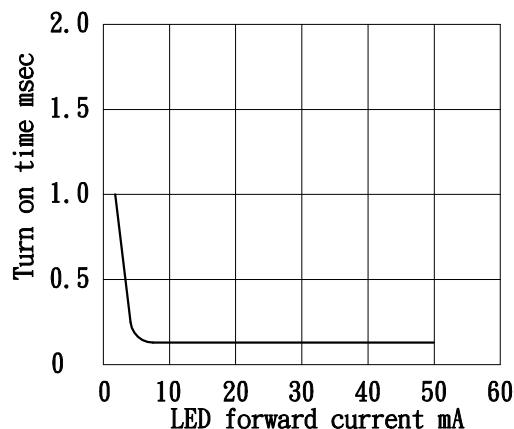
Ambient temperature: 25° C



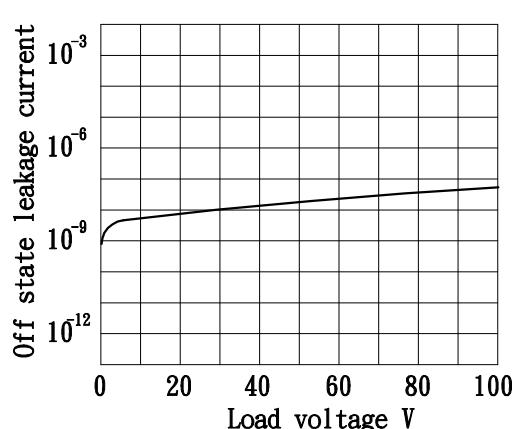
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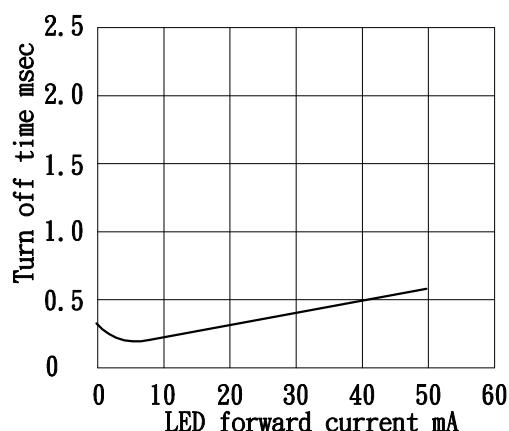
LED forward current vs. turn on time
Across terminals 3 and 4pin; Load voltage: 350V(DC); Continuous load current: 130mA(DC); Ambient temperature: 25° C



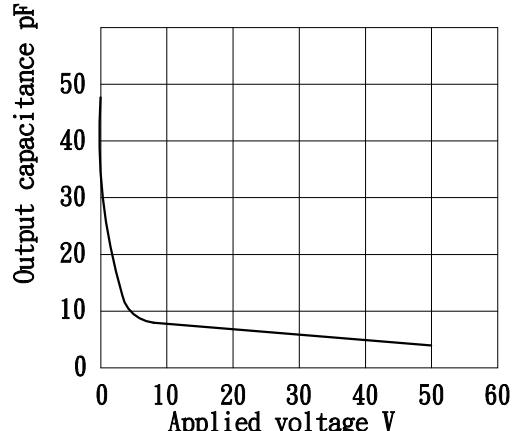
Off state leakage current
Across terminals 3 and 4pin
Ambient temperature: 25° C



LED forward current vs. turn off time
Across terminals 3 and 4pin; Load voltage: 350V(DC); Continuous load current: 130 mA(DC); Ambient temperature: 25° C



Applied voltage vs. output capacitance
Across terminals 3 and 4pin
Frequency: 1MHz; Ambient temperature: 25° C



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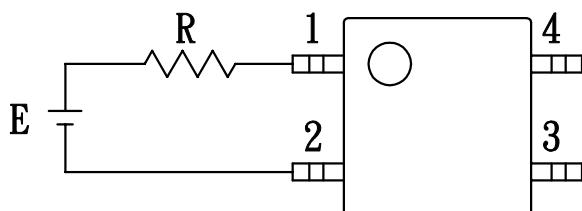
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USING METHODS

Examples of resistance value to control LED forward current I_F

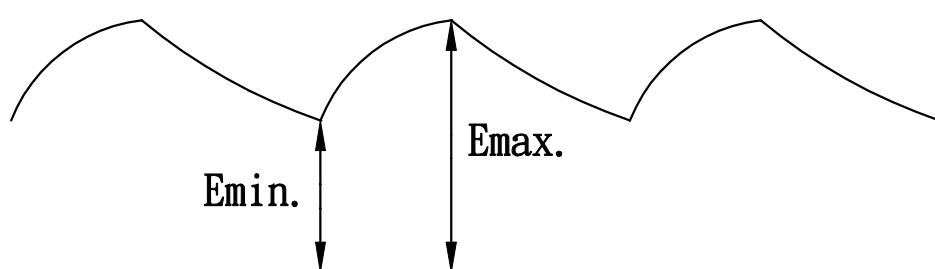
Photo MOSRELAY

($I_F = 5\text{mA}$)



E	R
3.3V	Approx. 240 ohm
5V	Approx. 540 ohm
12V	Approx. 1.8K ohm
15V	Approx. 2.4K ohm
24V	Approx. 4K ohm

- (1) LED forward current must be more than 5mA, at E min.
- (2) LED forward current must be less than 50mA, at E max.



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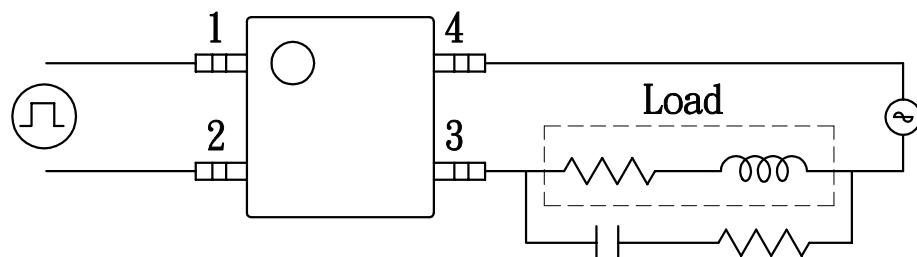
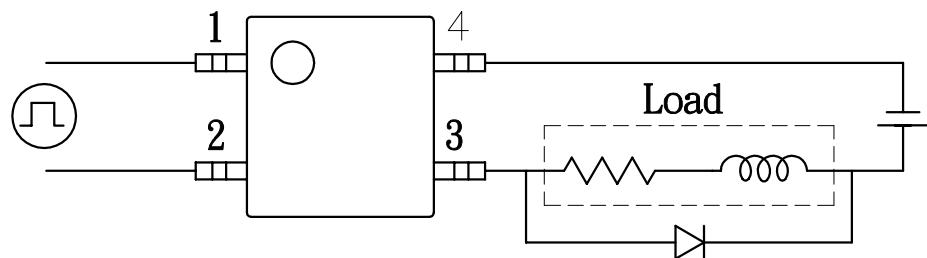
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USING METHODS

Regulate the spike voltage generated on the inductive load as follows



R-C Snubber